

AN7522

Dual 3-W BTL audio power amplifier

■ Overview

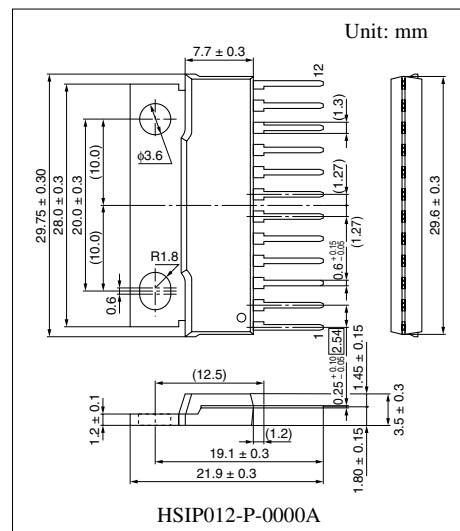
AN7522 is an audio power amplifier IC for the stereo system. In the BTL (balanced transformerless) method, fewer external parts and easier design for applications are required.

■ Features

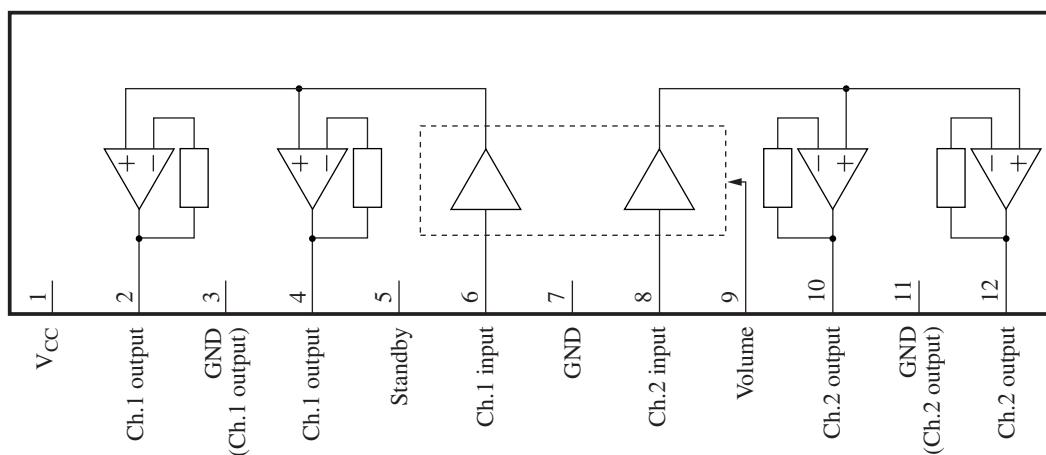
- 3-W output ($8\ \Omega$) with supply voltage of 8 V
 - On-chip standby function
 - On-chip volume function

■ Applications

- Televisions, audio equipment, personal computers, and active speakers



■ Block Diagram



■ Pin Descriptions

Pin No.	Descriptions	Pin No.	Descriptions
1	Supply voltage	7	Ground (input)
2	Ch.1 + output	8	Ch.2 input
3	Ground (output ch.1)	9	Volume (max. volume if this pin is open.)
4	Ch.1 – output	10	Ch.2 – output
5	Standby (standby state if this pin is open.)	11	Ground (output ch.2)
6	Ch.1 input	12	Ch.2 + output

■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage ^{*2}	V _{CC}	14	V
Supply current	I _{CC}	2.0	A
Power dissipation ^{*3}	P _D	1.92	W
Operating ambient temperature ^{*1}	T _{opr}	-25 to +70	°C
Storage temperature ^{*1}	T _{stg}	-55 to +150	°C

Note) *1: Except for the operating ambient temperature and storage temperature, all ratings are for T_a = 25°C.

*2: At no signal.

*3: The power dissipation shown is the value for T_a = 70°C.

■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V _{CC}	3.5 to 13.5	V

■ Electrical Characteristics at V_{CC} = 8.0 V, R_L = 8 Ω, f = 1 kHz, T_a = 25°C ± 2°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Quiescent circuit current	I _{CQ}	V _{IN} = 0 mV, Vol. = 0 V	—	45	100	mA
Standby current	I _{STB}	V _{IN} = 0 mV, Vol. = 0 V	—	1	10	μA
Output noise voltage *	V _{NO}	R _g = 10 kΩ, Vol. = 0 V	—	0.10	0.4	mV[rms]
Voltage gain	G _V	P _O = 0.5 W, Vol. = 1.25 V	31	33	35	dB
Total harmonic distortion	THD	P _O = 0.5 W, Vol. = 1.25 V	—	0.10	0.5	%
Maximum output power	P _{O1}	THD = 10%, Vol. = 1.25 V	2.4	3.0	—	W
Ripple rejection ratio *	RR	R _g = 10 kΩ, Vol. = 0 V, V _R = 1 V[rms], f _R = 120 Hz	30	50	—	dB
Output offset voltage	V _{OFF}	R _g = 10 kΩ, Vol. = 0 V	-250	0	250	mV
Volume attenuation rate *	Att	P _O = 0.5 W, Vol. = 0 V	70	85	—	dB
Channel balance 1	CB1	P _O = 0.5 W, Vol. = 1.25 V	-1	0	1	dB
Channel balance 2	CB2	P _O = 0.5 W, Vol. = 0.6 V	-3	0	3	dB
Intermediate voltage gain	G _{VM}	P _O = 0.5 W, Vol. = 0.6 V	20.5	23.5	26.5	dB
Channel crosstalk	CT	P _O = 0.5 W, Vol. = 1.25 V	40	55	—	dB

Note) *: In measuring, the filter for the range of 15 Hz to 30 kHz (12 dB/OCT) is used.

■ Terminal Equivalent Circuits

Pin No.	Pin name	Equivalent circuit	Voltage
1	V _{CC}	—	5.0 V
2	Ch.1 + output pin		2.15 V
3	GND		0 V
4	Ch.1 – output pin		2.15 V
5	Standby pin	<p>To the shock sound prevention circuit V_{RF} (\approx V_{CC})</p> <p>To the constant current circuit 1/2 V_{CC}</p>	5 V

■ Terminal Equivalent Circuits (continued)

Pin No.	Pin name	Equivalent circuit	Voltage
6	Ch.1 input pin		0 mV to 10 mV
7	GND		0 V
8	Ch.2 input pin		0 mV to 10 mV
9	Volume pin		—

■ Terminal Equivalent Circuits (continued)

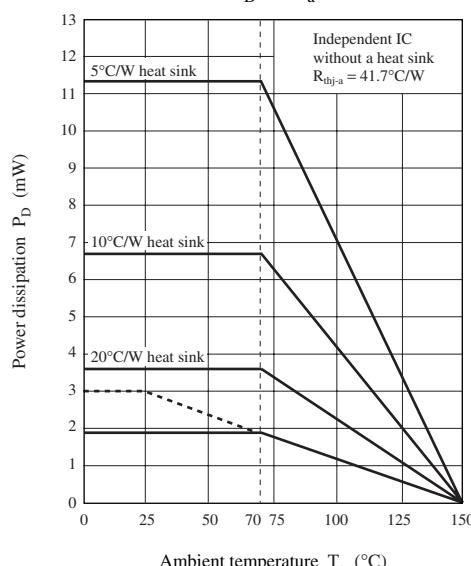
Pin No.	Pin name	Equivalent circuit	Voltage
10	Ch.2 – output pin		2.15 V
11	GND		0 V
12	Ch.2 + output pin		2.15 V

■ Usage Notes

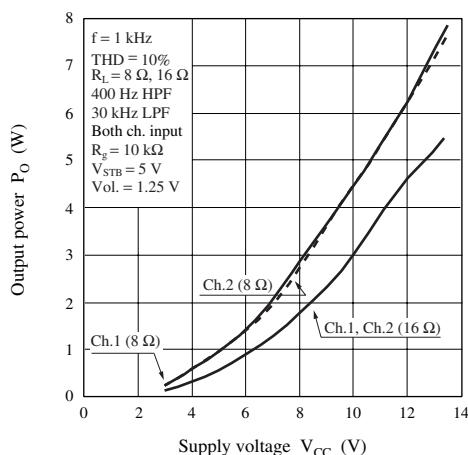
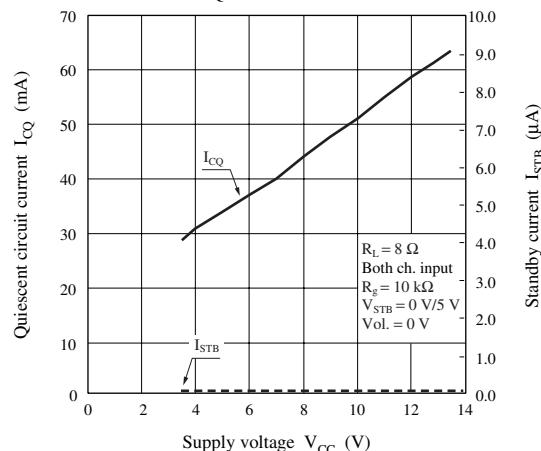
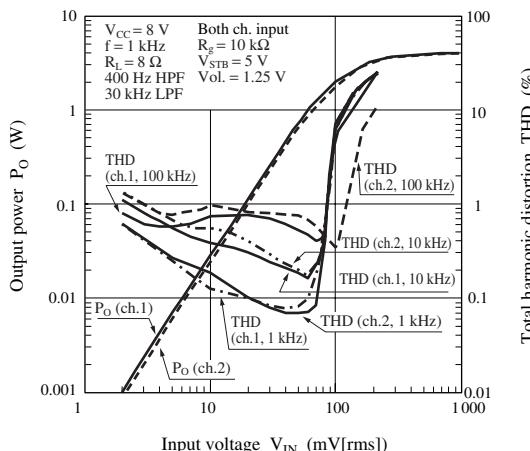
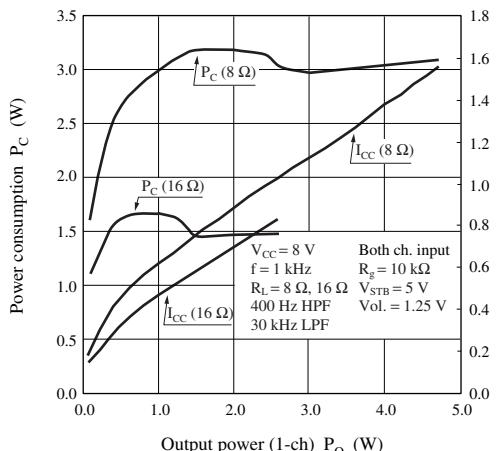
- Please avoid the short-circuits to V_{CC} , ground, or load short-circuit.
- Please connect the cooling fin with the GND potential.
- The thermal shutdown circuit operates at about $T_j = 150^\circ\text{C}$. However, the thermal shutdown circuit is reset automatically if the temperature drops.
- Please carefully design the heat radiation especially when you take out high power at high V_{CC} .
- Please connect only the ground of signal with the signal GND of the amplifier in the previous stage.

■ Technical Data

- $P_D - T_a$ curves of HSIP012-P-0000A

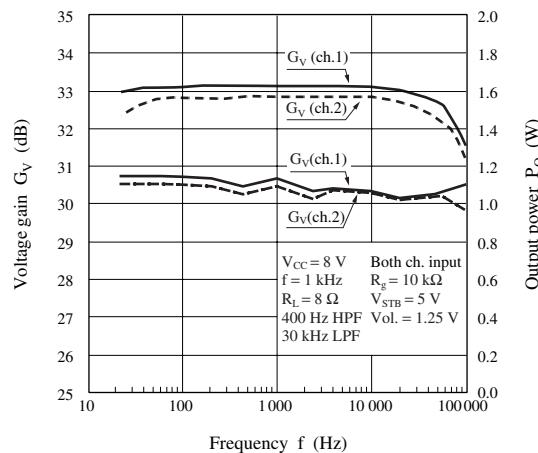
 $P_D - T_a$ 

- Main characteristics

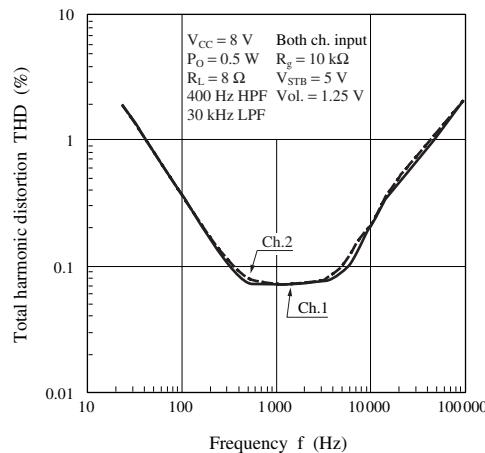
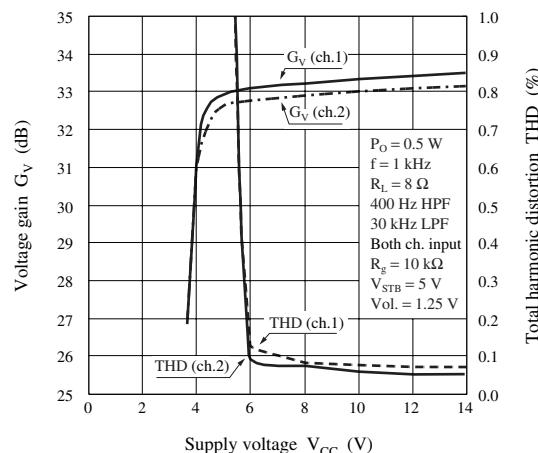
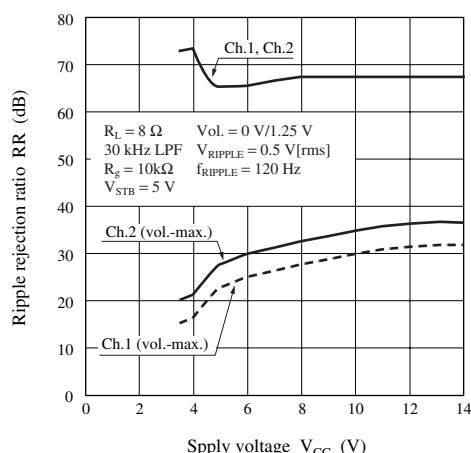
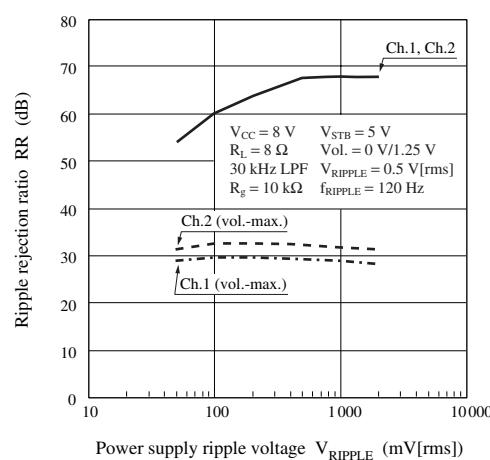
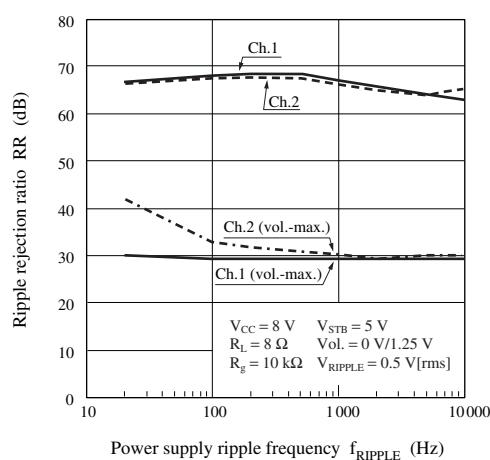
 $P_O - V_{CC}$  $I_{CQ}, I_{STB} - V_{CC}$  $P_O, THD - V_{IN}$  $P_C, I_{CC} - P_O$ 

■ Technical Data (continued)

- Main characteristics (continued)

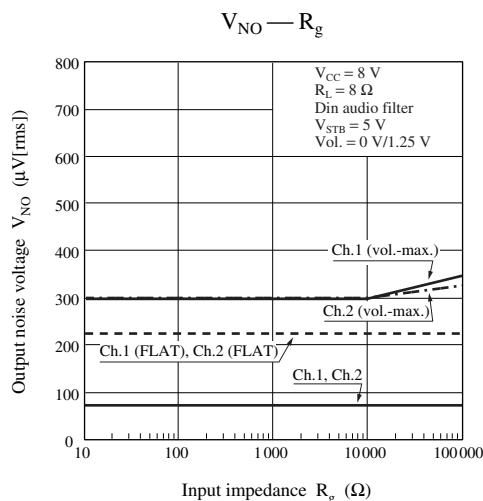
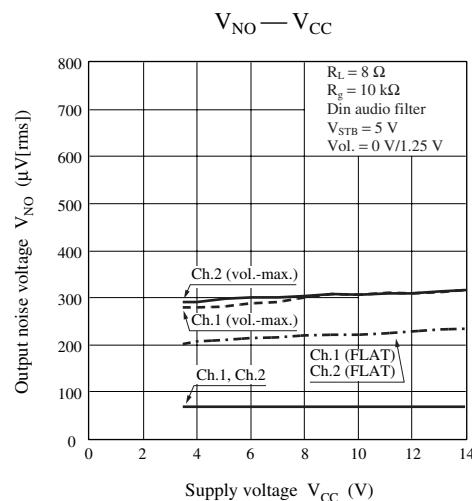
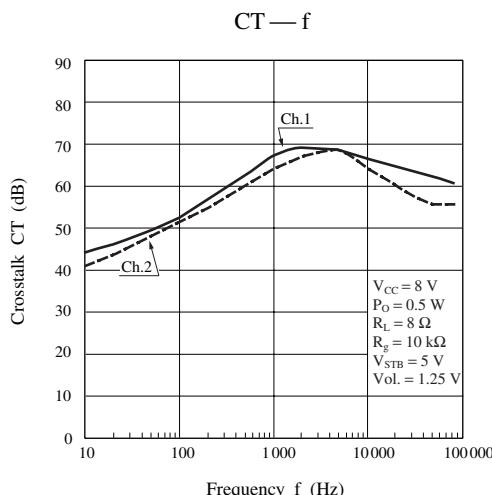
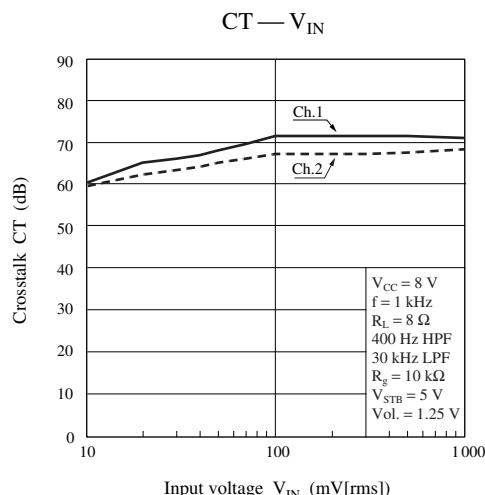
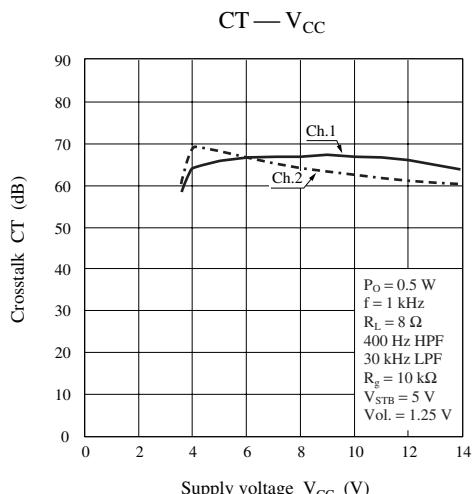
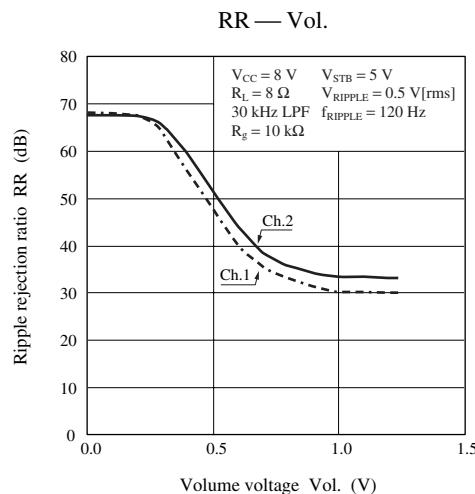
 G_V, P_O — f

THD — f

 $G_V, \text{THD} — V_{CC}$ RR — V_{CC} RR — V_{RIPPLE} RR — f_{RIPPLE} 

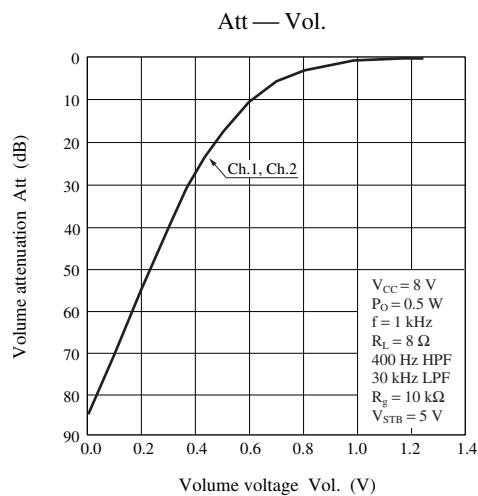
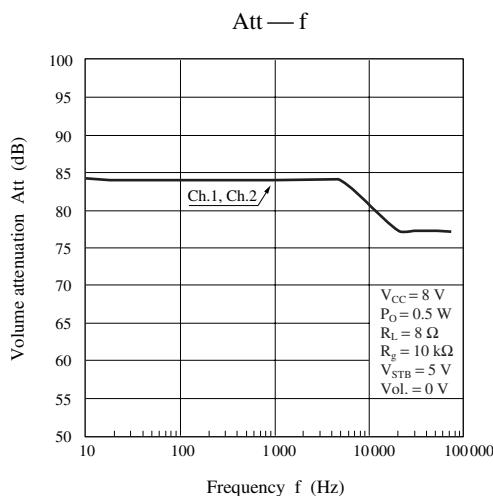
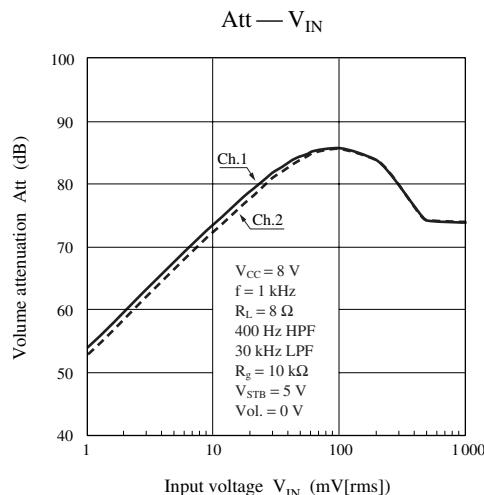
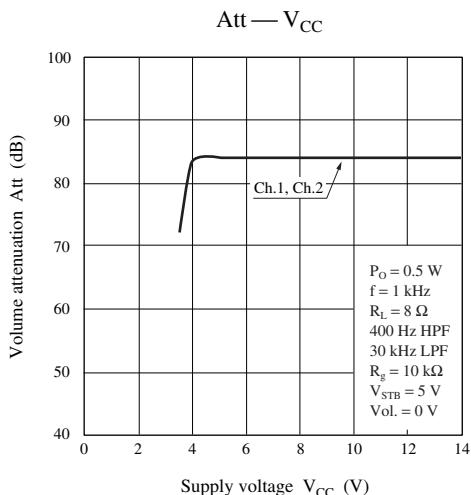
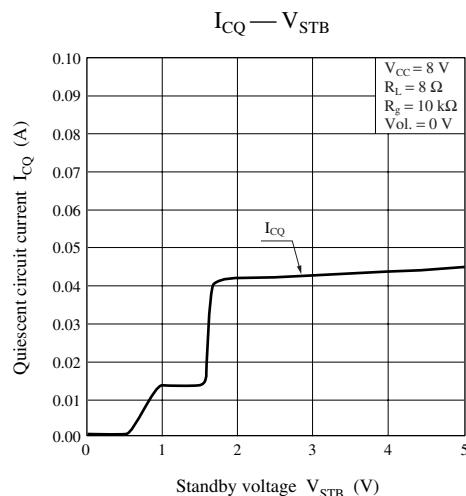
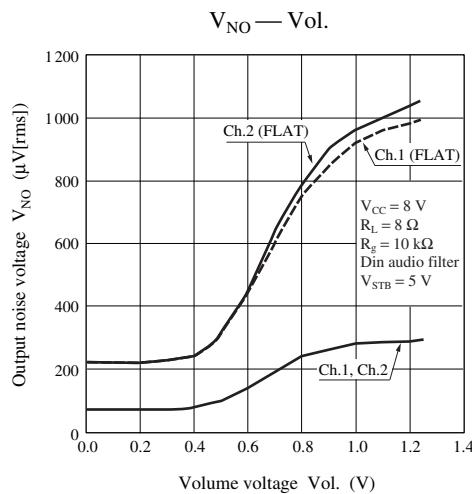
■ Technical Data (continued)

- Main characteristics (continued)



■ Technical Data (continued)

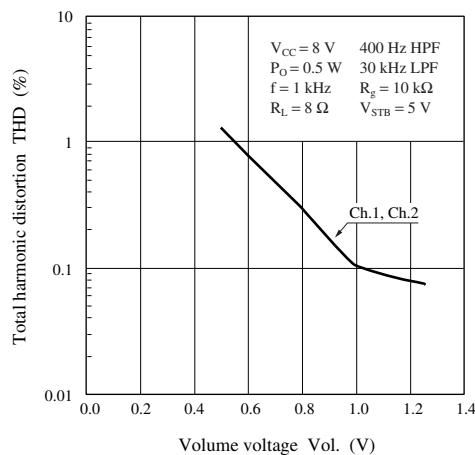
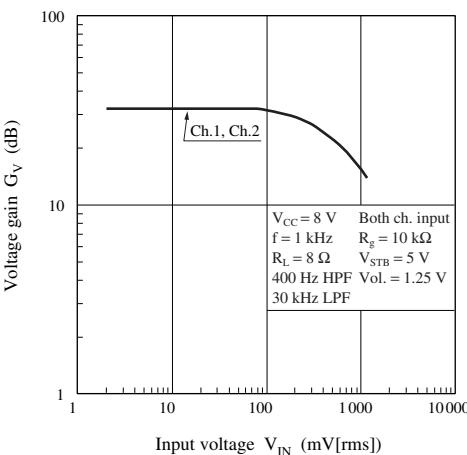
- Main characteristics (continued)



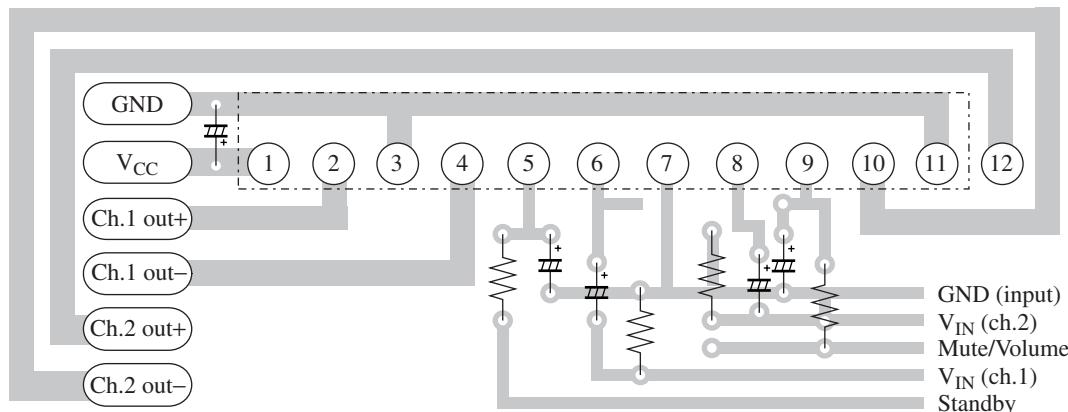
■ Technical Data (continued)

- Main characteristics (continued)

THD — Vol.

 $G_V — V_{IN}$ 

- Example of PCB pattern



■ Application Circuit Example

